14 W × 4-Channel BTL Power IC

HITACHI

ADE-207-116 1st. Edition

Description

The HA13151/HA13152 are high output and low distortion 4 ch BTL power IC designed for digital car audio.

At 13.2 V to 4 Ω load, this power IC provides output power 14 W with 10% distortion.

Functions

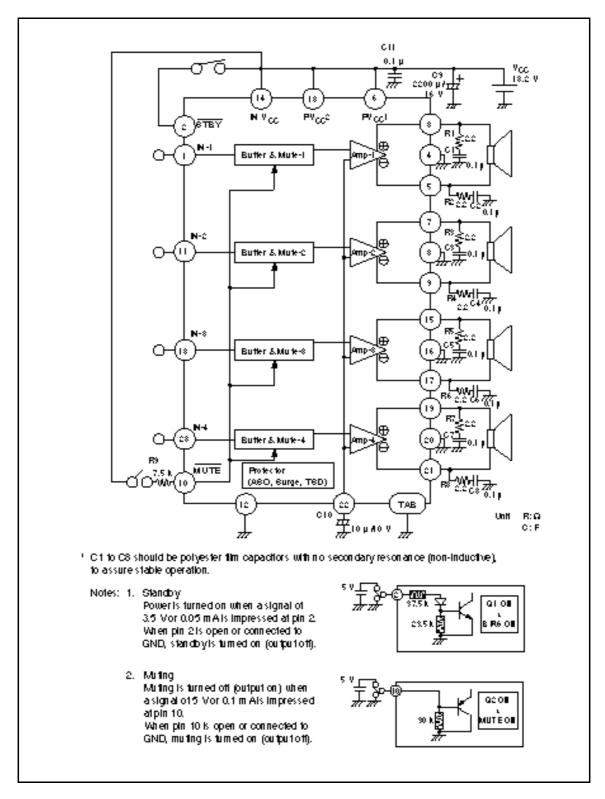
- 4 ch BTL power amplifiers
- Built-in standby circuit
- Built-in muting circuit
- Built-in protection circuit (surge, T.S.D, and ASO)

Features

- Few external parts lead to compact set-area possibility
- Popping noise minimized
- Low output noise
- Built-in high reliability protection circuit



Block Diagram



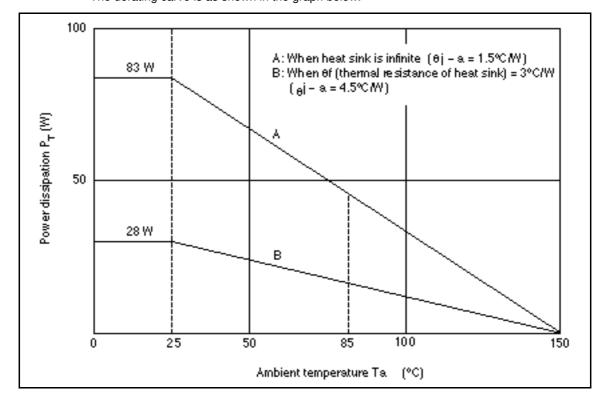
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Rating	Unit	Remarks	
ILCIII	CYIIIDOI	HUUHIN	Oille	HUHHUH	

			HA13151, HA13152
Operating supply voltage	V_{cc}	18	V
Supply voltage when no signal*1	V _{cc} (DC)	26	V
Peak supply voltage*2	V _{cc} (PEAK)	50	V
Output current*3	I _o (PEAK)	3	Α
Power dissipation*4	P _T	83	W
Junction temperature	Tj	150	°C
Operating temperature	Topr	-30 to +85	°C
Storage temperature	Tstg	-55 to +125	°C

Notes: 1. Tolerance within 30 seconds

- 2. Tolerance in surge pulse waveform
- 3. Value per 1 channel
- 4. Value when attached on the infinite heat sink plate at Ta = 25 °C. The derating carve is as shown in the graph below.



Electrical Characteristics (V $_{CC}$ = 13.2 V, f = 1 kHz, R $_{L}$ = 4 $\Omega,$ Rg = 600 $\Omega,$ Ta = 25°C)

HA13151

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Quiescent current	I _Q 1	_	270	_	mA	Vin = 0
Output offset voltage	ΔV_Q	-300	0	+300	mV	
Gain	G _v	30.5	32	33.5	dB	
Gain difference between channels	ΔG_{v}	-1.5	0	+1.5	dB	
Rated output power	Po	_	14	_	W	$V_{CC} = 13.2 \text{ V}$ THD = 10%, $R_L = 4 \Omega$
Max output power	Pomax	_	22	_	W	V_{CC} = 13.7 V THD = Max, R_L = 4 Ω
Total harmonic distortion	T.H.D.	_	0.05	_	%	Po = 3 W
Output noise voltage	WBN	_	0.15	_	mVrms	Rg = 0Ω BW = $20 \text{ to } 20 \text{ kHz}$
Ripple rejection	SVR	_	55	_	dB	Rg = 600Ω , f = $120 Hz$
Channel cross talk	C.T.	_	70	_	dB	Rg = 600Ω Vout = 0 dBm
Input impedance	Rin	_	25	_	kΩ	
Standby current	I _Q 2	_	_	200	μΑ	
Standby control voltage (high)	V_{STH}	3.5	_	V _{cc}	V	
Standby control voltage (low)	V_{STL}	0	_	1.5	V	
Muting control voltage (high)	V_{MH}	3.5	_	V _{CC}	V	
Muting control voltage (low)	V_{ML}	0	_	1.5	V	
Muting attenuation	ATTM	_	70		dB	Vout = 0 dBm

HA13152

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Quiescent current	I _Q 1	_	270	_	mA	Vin = 0
Output offset voltage	$\Delta V_{\scriptscriptstyle Q}$	-300	0	+300	mV	
Gain	G _v	38.5	40	41.5	dB	
Gain difference between channels	ΔG_{v}	-1.5	0	+1.5	dB	
Rated output power	Ро	_	14	_	W	$V_{CC} = 13.2 \text{ V}$ THD = 10%, $R_L = 4 \Omega$
Max output power	Pomax	_	22	_	W	V_{CC} = 13.7 V THD = Max, R_L = 4 Ω
Total harmonic distortion	T.H.D.	_	0.05	_	%	Po = 3%
Output noise voltage	WBN	_	0.25	_	mVrms	Rg = 0Ω BW = $20 \text{ to } 20 \text{ kHz}$
Ripple rejection	SVR	_	45	_	dB	Rg = 600 Ω , f = 120 Hz
Channel cross talk	C.T.	_	60	_	dB	$Rg = 600 \Omega$ $Vout = 0 dBm$
Input impedance	Rin	_	25	_	kΩ	
Standby current	I _Q 2	_	_	200	μΑ	
Standby control voltage (high)	V_{STH}	3.5	_	V _{cc}	V	
Standby control voltage (low)	V_{STL}	0	_	1.5	V	
Muting control voltage (high)	V_{MH}	3.5	_	V _{CC}	V	
Muting control voltage (low)	V_{ML}	0	_	1.5	V	
Muting attenuation	ATTM	_	60	_	dB	Vout = 0 dBm

Pin Explanation

Pin No.	Symbol	Functions	Input Impedance	DC Voltage	Equivalence Circuit
1	IN1	CH1 INPUT	25 kΩ (Typ)	0 V	1 m m m m m m m m m m m m m m m m m m m
11	IN2	CH2 INPUT	<u></u>		
13	IN3	CH3 INPUT			
23	IN4	CH4 INPUT			
2	STBY	Standby control	90 kΩ (at Trs. cutoff)	_	23.5 k
3	OUT1 +	CH1 OUTPUT		V _{cc} /2	3
5	OUT1 –				
7	OUT2 +	CH2 OUTPUT			
9	OUT2 –				
15	OUT3 +	CH3 OUTPUT			
17	OUT3 -	0114 011=-:-			
19	OUT4 +	CH4 OUTPUT			
21	OUT4 –				
10	MUTE	Muting control	25 kΩ (Typ)	_	10

Pin Explanation (cont)

Pin No.	Symbol	Functions	Input Impedance	DC Voltage	Equivalence Circuit
22	RIPPLE	Bias stability	_	V _{cc} /2	
6	PV _{cc} 1	Power of output stage	_	V _{cc}	_
18	PV _{cc} 2				
14	INV _{cc}	Power of input stage	_	V _{cc}	_
4	CH1 GND	CH1 power GND	_	_	_
8	CH2 GND	CH2 power GND	_		
16	CH3 GND	CH3 power GND	_		
20	CH4 GND	CH4 power GND	_		
12	IN GND	Input signal GND	_	_	_

Point of Application Board Design

- 1. Notes on Application Board's Pattern Design
- For increasing stability, the connected line of V_{CC} and OUTGND is better to be made wider and lower impedance.
- For increasing stability, it is better to place the capacitor between V_{CC} and GND (0.1 μF) close to IC.
- For increasing stability, it is better to place C1 to C8 and R1 to R8, which are for stopping oscillation, close to IC.
- It is better to place the grounding of resistor (Rg), between input line and ground, close to INGND (Pin 12) because if OUTGND is connected to the line between Rg and INGND, THD will become worse due to current from OUTGND.

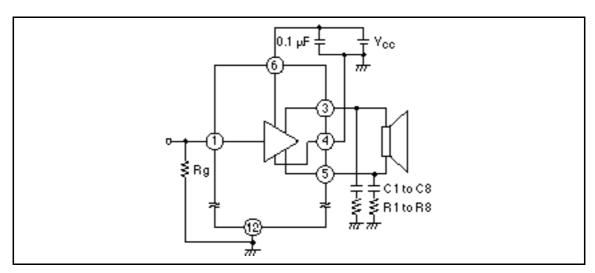


Figure 1 Notes on Application Board's Pattern Design

2. How to Reduce the Popping Noise by Muting Circuit

At normal operating circuit, Muting circuit operates at high speed under $1~\mu s$.

In case popping noise becomes a problem, it is possible to reduce the popping noise by connecting capacitor, which determines the switching time constant, between pin 10 and GND. (Following figure 2)

We recommend value of capacitor greater then 1 μ F.

Also transitional popping noise can be reduced sharply by muting before V_{CC} and Standby are ON/OFF.

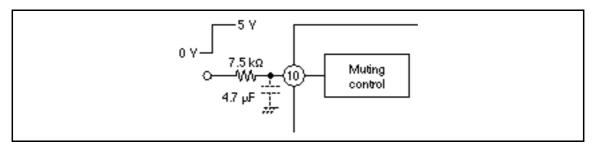
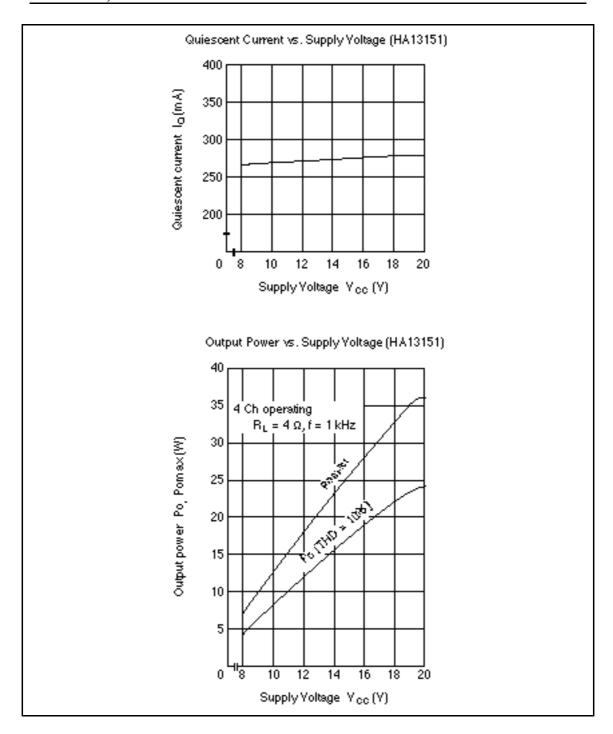
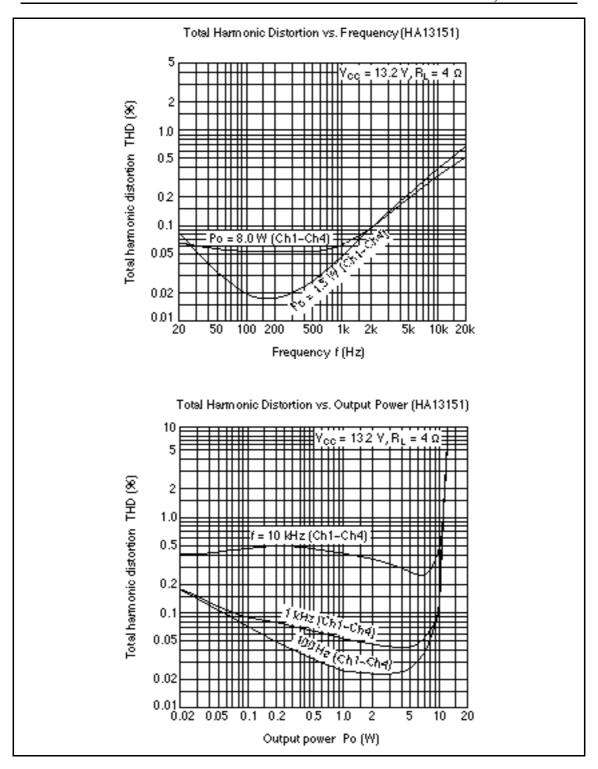


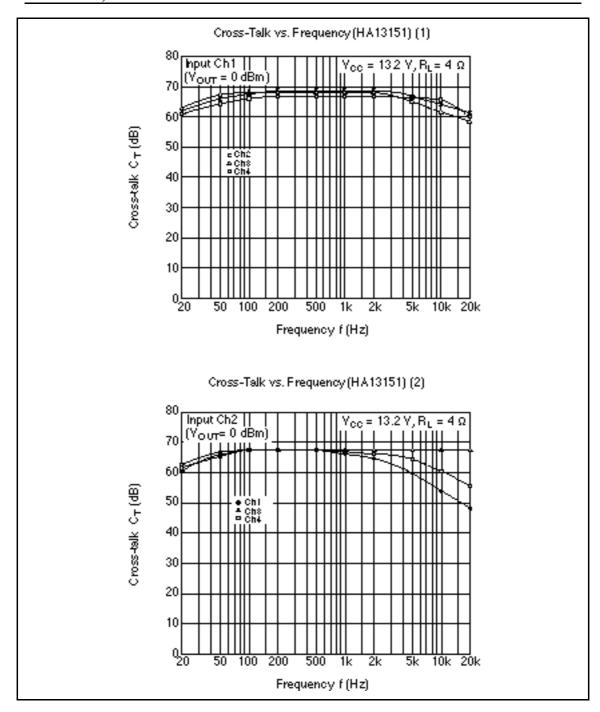
Figure 2 How to use Muting Circuit

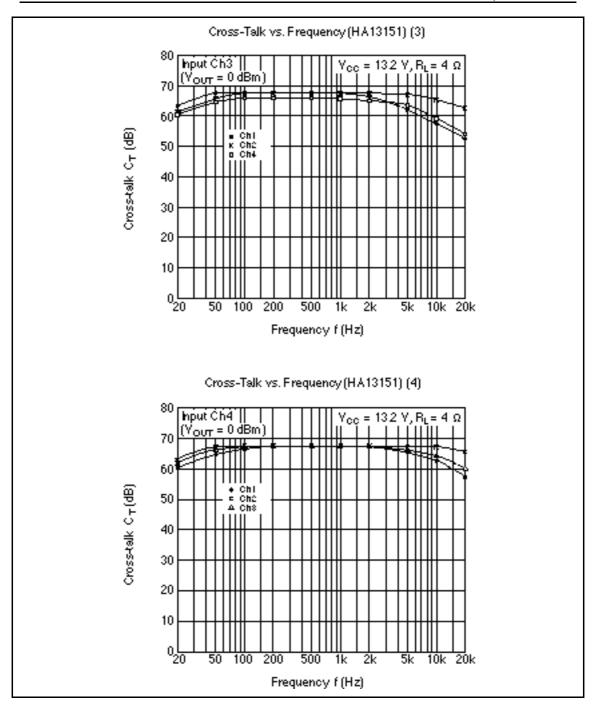
Table 1 Muting ON/OFF Time

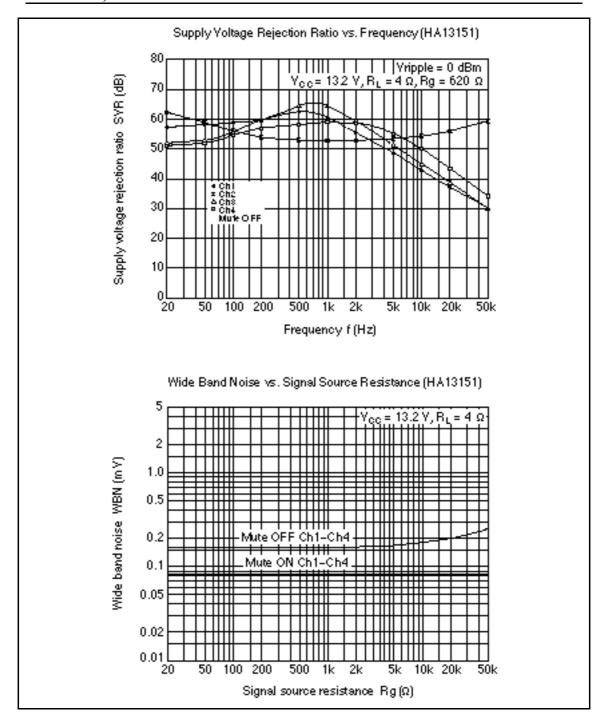
C (μF)	ON Time	OFF Time
nothing	under 1 μs	under 1 μs
0.47	2 ms	2 ms
4.7	19 ms	19 ms

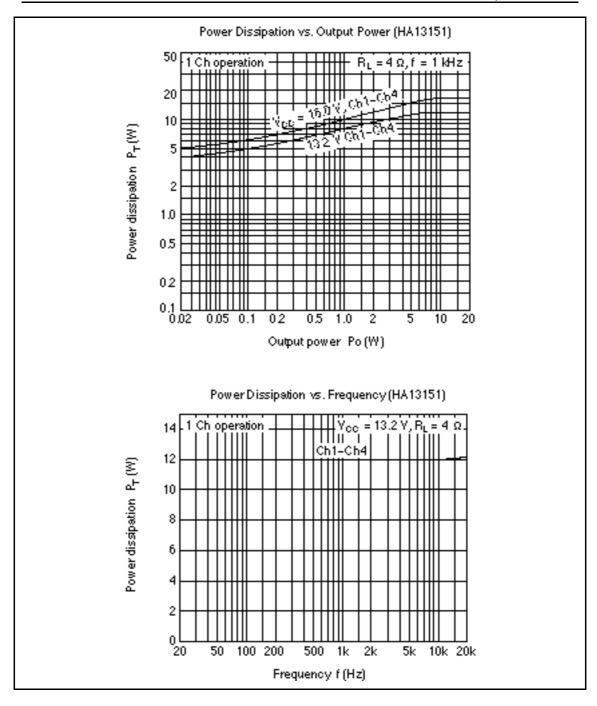


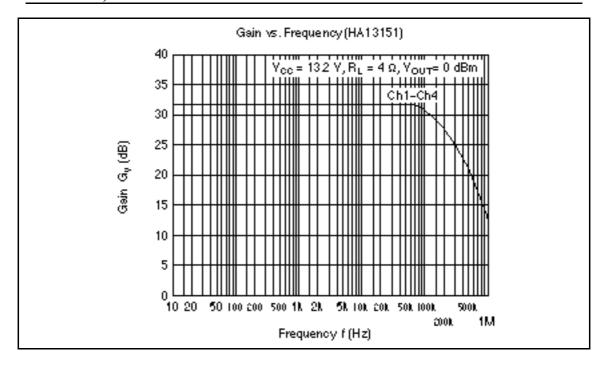


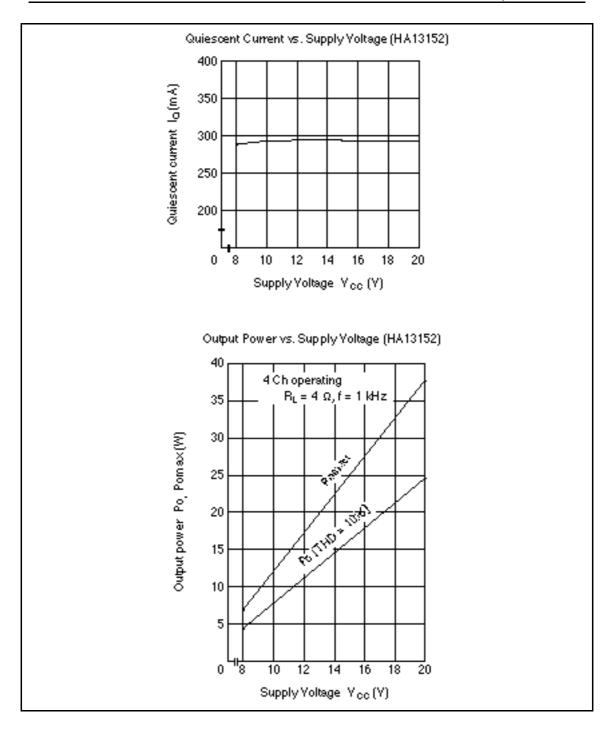


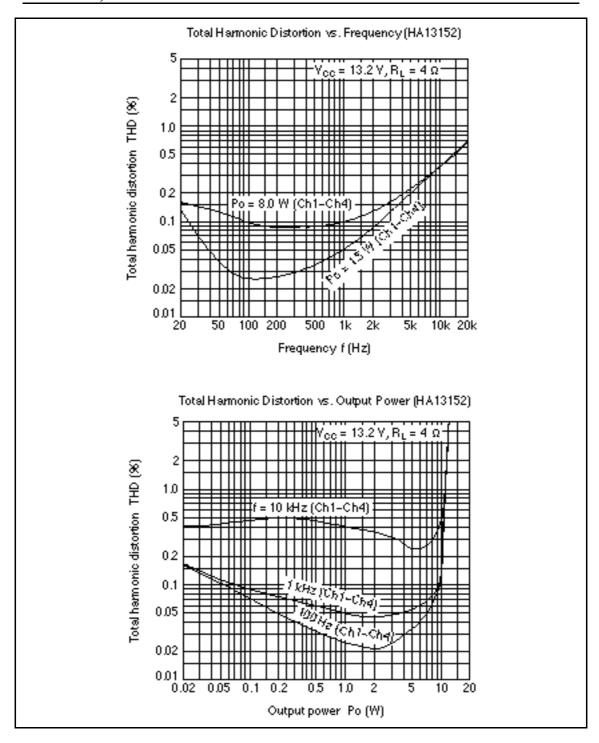


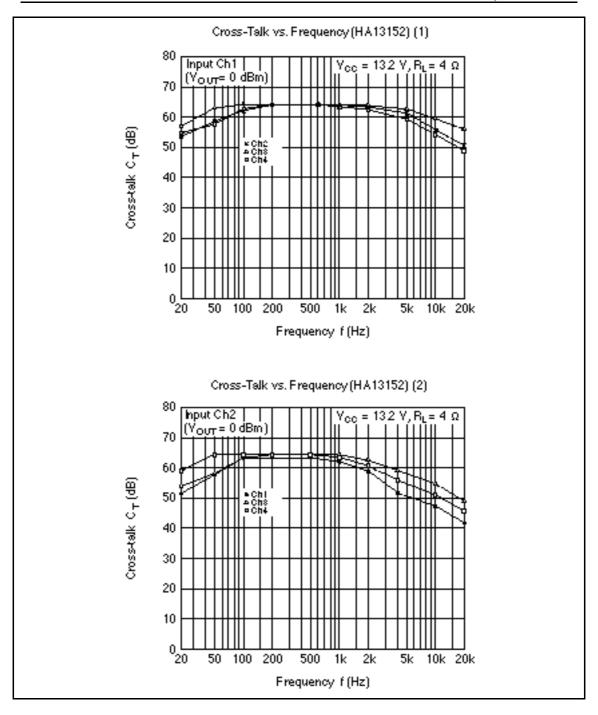


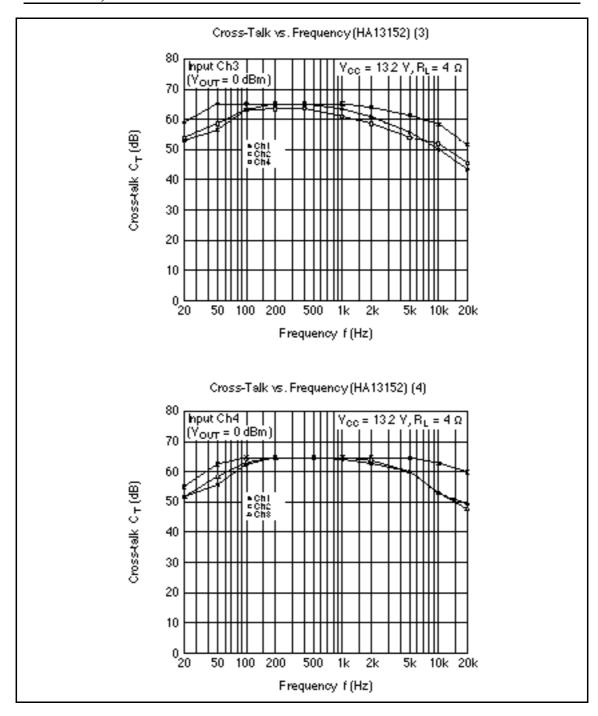


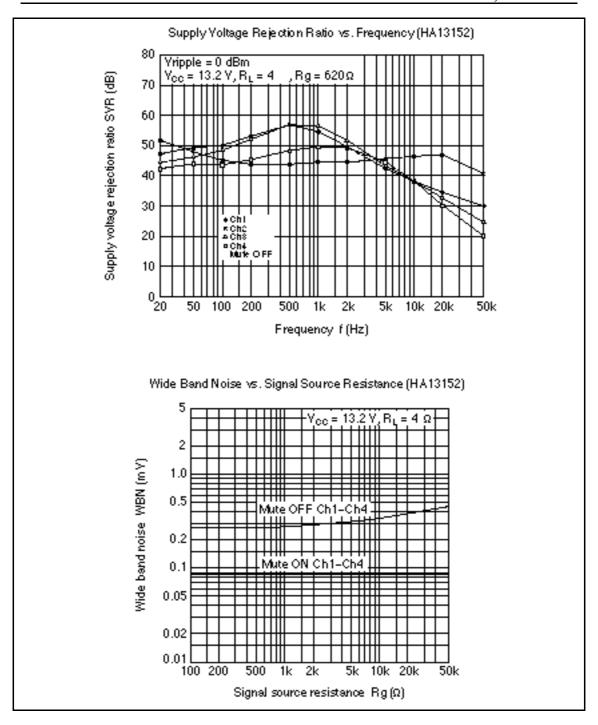


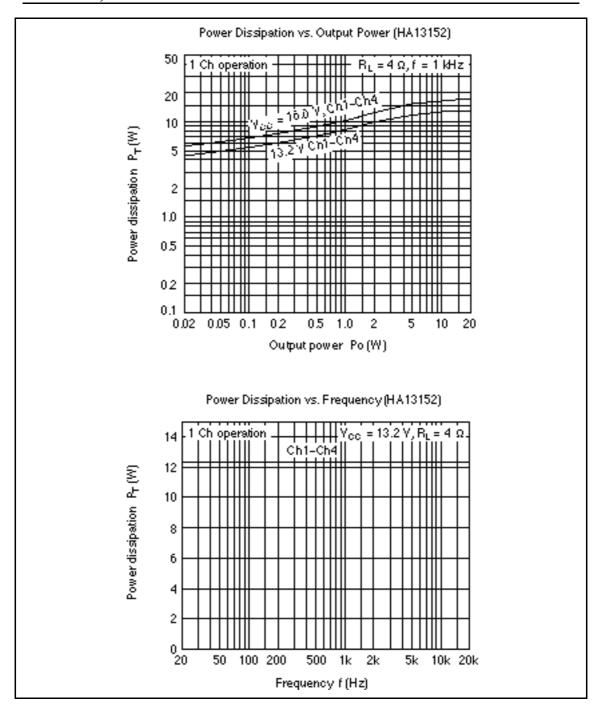


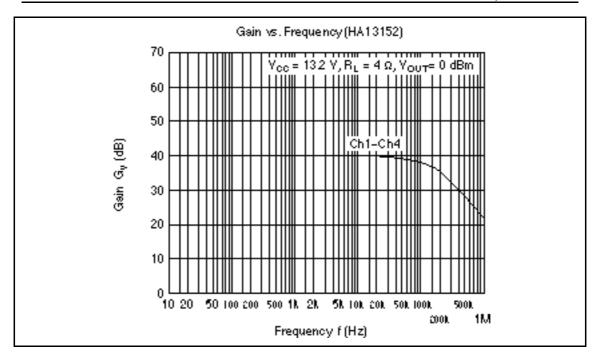












When using this document, keep the following in mind:

- 1. This document may, wholly or partially, be subject to change without notice.
- 2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
- 3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
- 4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
- 5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
- 6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
Nepon Bidg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokiyo 100, Japan
Tet Tokyo (03, 3270-2414
Fex: (03, 3270-5409

For further in formellon write to:

Hitechi Americe, Ltd. Semiconductor & IC Div. 2000 Sierre Point Perkwey Briebene, CA. 94005-4835 U.S.A.

Tet +15-589-8300 Fex: +15-583-4207 Hitechi Burope GmbH
Bedronic Componente Group
Cartinertal Burope
Darnecher Streße 3
D-85622 Feldkirchen
München
Tet 089-9 94 80-0
Fex: 089-9 29 30 00

Hitachi Burope Ltd.
Bedronic Componenta Dw.
Northern Burope Headquartera
Whitebrook Park
Lower Cook ham Road
Heidenhead
Barkshire SL68YA
Urited Kingdom
Tet 0628-858000
Fex: 0628-778322

Hitachi Asia Pta, Ltd 45 Collyer Quay \$20-00 Hitachi Tower Snappore 0404 Tat 535-2400 Fex: 535-4533

Hischi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Centre, Harbour City, Centon Road Taim She Taul, Kowloon Hong Kong Tet 27:350218 Fax: 27:30607 f

This datasheet has been downloaded from:

www. Data sheet Catalog.com

Datasheets for electronic components.